Introduction to CMOS VLSI Design

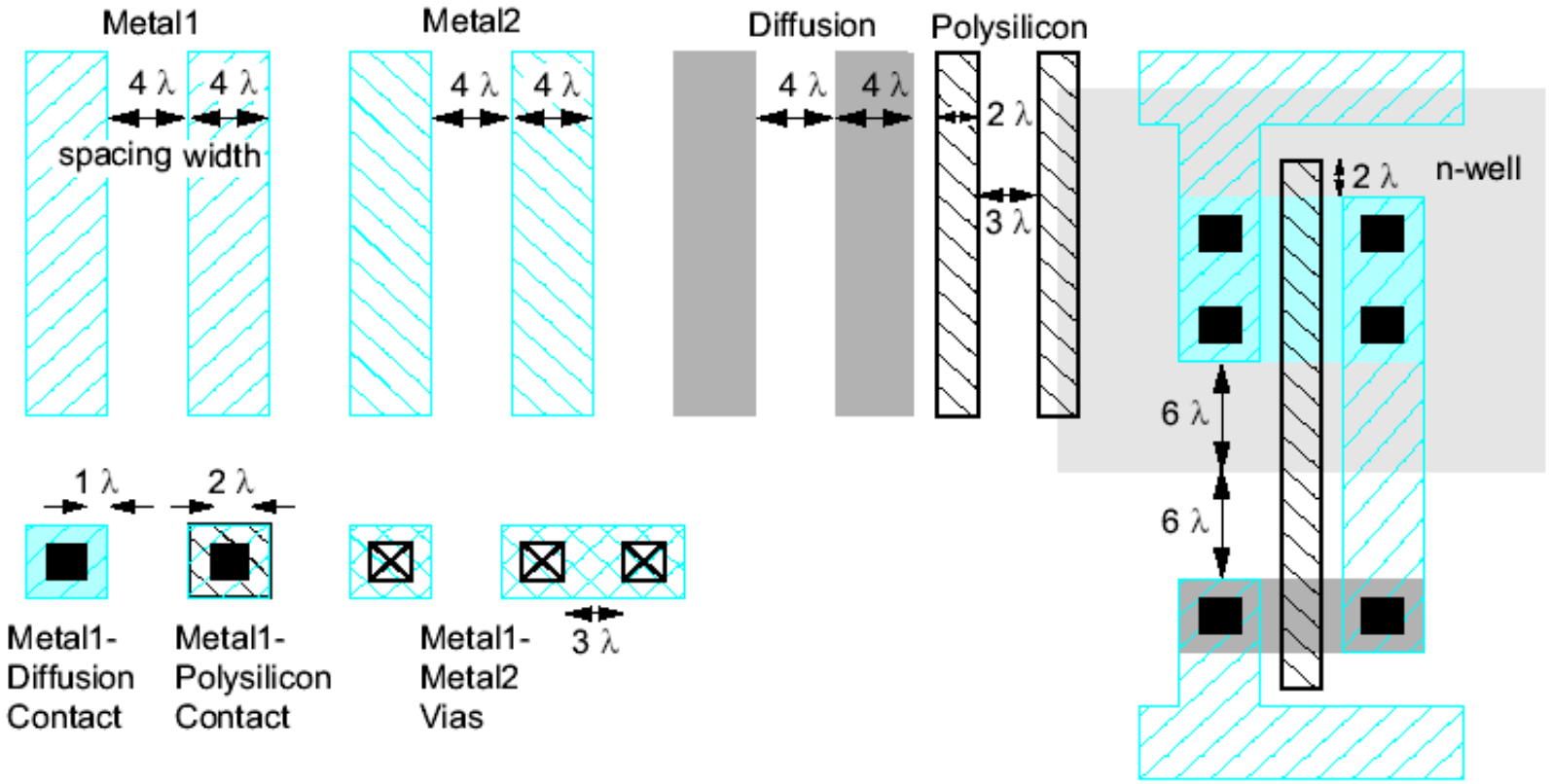
CMOS Design Layout

Layout

- Chips are specified with set of masks
- Minimum dimensions of masks determine transistor size (and hence speed, cost, and power)
- Feature size *f* = distance between source and drain
  - Set by minimum width of polysilicon
- Feature size improves 30% every 3 years or so
- Normalize for feature size when describing design rules
- Express rules in terms of $\lambda = f/2$
  - E.g. λ = 0.3 μm in 0.6 μm process

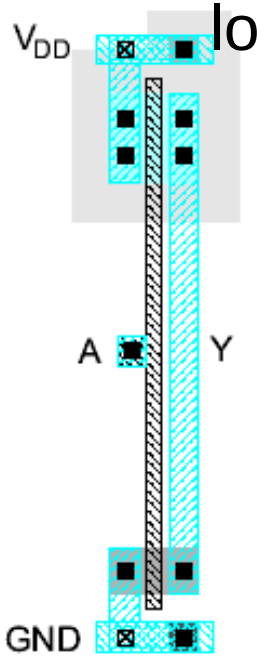
Simplified Design Rules

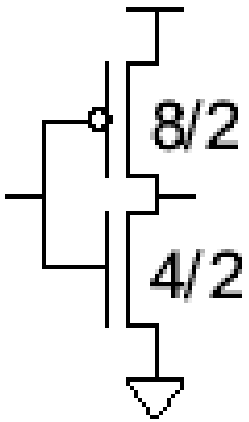
- Conservative rules to get you started

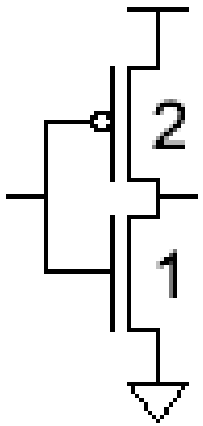


Inverter Layout

- Transistor dimensions specified as Width / Length
  - Minimum size is 4λ / 2λ, sometimes called 1 unit
  - In *f* = 0.6 μm process, this is 1.2 μm wide, 0.6 μm long







Summary

- MOS Transistors are stack of gate, oxide, silicon
- Can be viewed as electrically controlled switches
- Build logic gates out of switches
- Draw masks to specify layout of transistors

- Now you know everything necessary to start designing schematics and layout for a simple chip!